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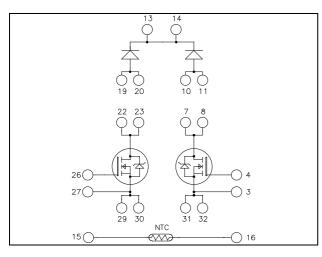
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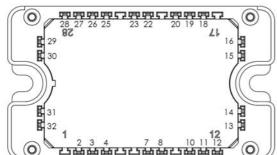
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### Dual boost chopper Super Junction MOSFET Power Module





All multiple inputs and outputs must be shorted together Example: 13/14 ; 29/30 ; 22/23 ...

# APTC60VDAM24T3G

### $V_{DSS} = 600V$

 $R_{DSon} = 24m\Omega \max @ Tj = 25^{\circ}C$ 

### $I_D = 95A @ Tc = 25^{\circ}C$

#### Application

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction (PFC)
- Interleaved PFC

#### Features

#### • Super junction MOSFET

- Ultra low R<sub>DSon</sub>
- Low Miller capacitance
- Ultra low gate charge
- Avalanche energy rated
- Very rugged
- Kelvin source for easy drive
- Very low stray inductance
- Internal thermistor for temperature monitoring

#### Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Each leg can be easily paralleled to achieve a single Boost of twice the current capability
- RoHS Compliant

### All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Absolute maximum ratings (per super junction MOSFET)

Symbol	Parameter		Max ratings	Unit
V <sub>DSS</sub>	Drain - Source Voltage		600	V
т	Cartingen Drain Connect	$T_c = 25^{\circ}C$	95	
ID	I <sub>D</sub> Continuous Drain Current	$T_c = 80^{\circ}C$	70	Α
I <sub>DM</sub>	Pulsed Drain current	260	7	
V <sub>GS</sub>	Gate - Source Voltage		±20	V
R <sub>DSon</sub>	Drain - Source ON Resistance		24	mΩ
PD	Power Dissipation $T_c = 25^{\circ}C$		462	W
I <sub>AR</sub>	Avalanche current (repetitive and non repetitive)		15	Α
EAR	Repetitive Avalanche Energy		3	mI
E <sub>AS</sub>	Single Pulse Avalanche Energy		1900	mJ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

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### Electrical Characteristics (per super junction MOSFET)

Symbol	<i>Characteristic</i>	Test Conditions	Min	Тур	Max	Unit
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 600V$			350	μΑ
R <sub>DS(on)</sub>	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 47.5A$			24	mΩ
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 5mA$	2.1	3	3.9	V
I <sub>GSS</sub>	Gate – Source Leakage Current	$V_{GS} = \pm 20 V, V_{DS} = 0V$			200	nA

### Dynamic Characteristics (per super junction MOSFET)

Symbol	<i>Characteristic</i>	Test Conditions	Min	Тур	Max	Unit
C <sub>iss</sub>	Input Capacitance	$V_{GS} = 0V$ ; $V_{DS} = 25V$		14.4		nF
Coss	Output Capacitance	f = 1 MHz		17		m
Qg	Total gate Charge	$V_{GS} = 10V$		300		
$Q_{\mathrm{gs}}$	Gate – Source Charge	$V_{Bus} = 300V$		68		nC
$Q_{gd}$	Gate – Drain Charge	$I_D = 95A$		102		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching (125°C)		21		
Tr	Rise Time	$V_{GS} = 10V$		30		
T <sub>d(off)</sub>	Turn-off Delay Time	$V_{Bus} = 400V$ $I_D = 95A$ $R_G = 2.5\Omega$		100		ns
$T_{\mathrm{f}}$	Fall Time			45		
Eon	Turn-on Switching Energy	Inductive switching @ $25^{\circ}C$ $V_{GS} = 10V$ ; $V_{Bus} = 400V$		1350		T
$E_{\text{off}}$	Turn-off Switching Energy	$I_D = 95A; R_G = 2.5\Omega$		1040		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C $V_{GS} = 10V$ ; $V_{Bus} = 400V$ $I_D = 95A$ ; $R_G = 2.5\Omega$		2200		<b>I</b>
$E_{\mathrm{off}}$	Turn-off Switching Energy			1270		μJ
$R_{thJC}$	Junction to Case Thermal Resistan	ice			0.27	°C/W

### Chopper diode ratings and characteristics (per diode)

Symbol	Characteristic Test Conditions		Min	Тур	Max	Unit	
V <sub>RRM</sub>	Peak Repetitive Reverse Voltage					600	V
I <sub>RM</sub>	Reverse Leakage Current	$V_{R} = 600 V$				100	μΑ
$I_{\rm F}$	DC Forward Current		$T_c = 80^{\circ}C$		100		А
		$I_F = 100A$			1.6	2	
$V_{\rm F}$	Diode Forward Voltage	$I_F = 200A$			2		V
		$I_F = 100A$	$T_j = 125^{\circ}C$		1.3		
t <sub>rr</sub>	Reverse Recovery Time	$I_{-} = 100 \text{ A}$	$T_j = 25^{\circ}C$		160		ng
			$T_j = 125^{\circ}C$		220		ns
Q <sub>rr</sub>	Reverse Recovery Charge	di/dt=200A/µs	$T_j = 25^{\circ}C$		290		nC
			$T_j = 125^{\circ}C$		1530		ше
R <sub>thJC</sub>	Junction to Case Thermal Resistance					0.55	°C/W

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### Thermal and package characteristics

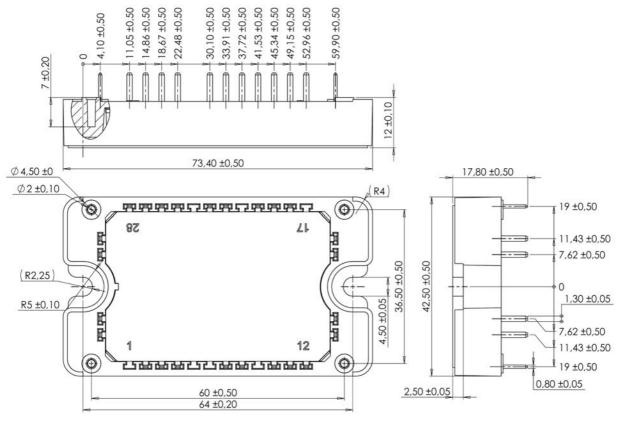
Symbol	Characteristic			Min	Max	Unit
VISOL	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000		V
TJ	Operating junction temperature range			-40	150	
T <sub>JOP</sub>	Recommended junction temperature under switching conditions			-40	T <sub>J</sub> max -25	°C
T <sub>STG</sub>	Storage Temperature Range			-40	125	C
T <sub>C</sub>	Operating Case Temperature			-40	125	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package Weight				110	g

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic		Min	Тур	Max	Unit
R <sub>25</sub>	Resistance @ 25°C	ce @ 25°C		50		kΩ
$\Delta R_{25}/R_{25}$				5		%
B <sub>25/85</sub>	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta B/B$		T <sub>C</sub> =100°C		4		%

$$R_{T} = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$
 T: Thermistor temperature  
R<sub>T</sub>: Thermistor value at T

#### Package outline (dimensions in mm)



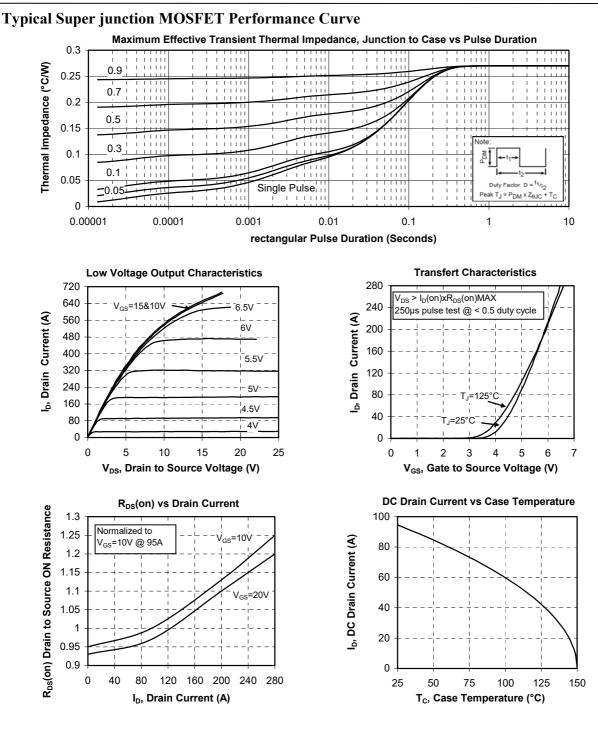
See application note 1906 - Mounting Instructions for SP3F Power Modules on www.microsemi.com

www.microsemi.com

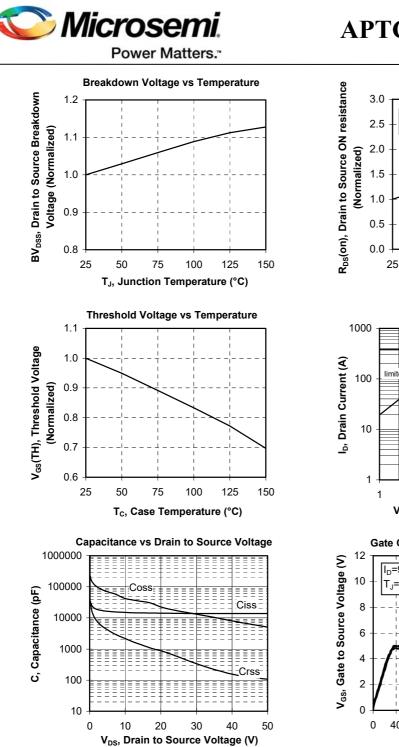
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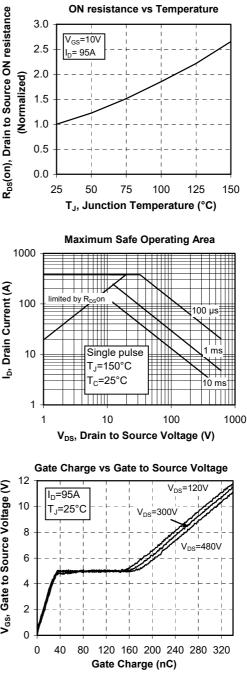


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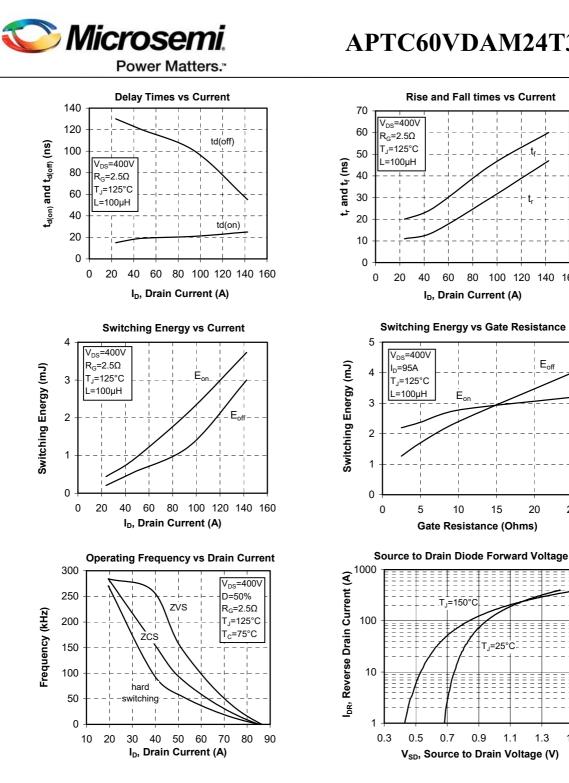


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60

10

=150 °C

80 100 120 140 160

 $\mathsf{E}_{\mathsf{off}}$ 

20

15

т<sub>л</sub>=25°с

1.1

0.9

0.7

25

1.5

1.3

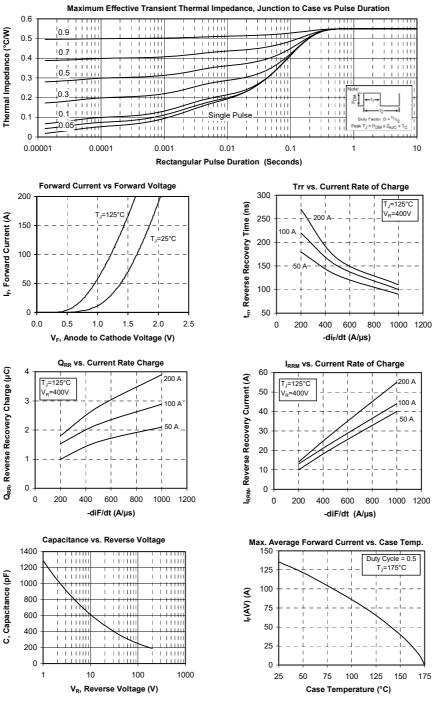


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#### Typical chopper diode performance curve



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